## MUR420S – MUR460S Taiwan Semiconductor

# 4A, 200V - 600V Ultra Fast Surface Mount Rectifier

## FEATURES

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• Glass passivated chip junction

**IICONDUCTOR** 

- Ideal for automated placement
- Ultra Fast recovery time for high efficiency
- Moisture sensitivity level: level 1, per J-STD-020
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

## **APPLICATIONS**

- High frequency rectification
- Freewheeling application
- Switching mode converters and inverters in computer, and telecommunication

## **MECHANICAL DATA**

- Case: DO-214AB (SMC)
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 2 whisker test
- Polarity: Indicated by cathode band
- Weight: 0.250g (approximately)

KEY PARAMETERS			
VALUE	UNIT		
4 A 200 - 600 V			
		75	А
175°CDO-214AB (SMC)Single die			
			VALUE           4           200 - 600           75           175           DO-214AB





DO-214AB (SMC)



ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25°C unless otherwise noted)					
PARAMETER	SYMBOL	MUR420S	MUR440S	MUR460S	UNIT
Marking code on the device		MUR420S	MUR440S	MUR460S	
Repetitive peak reverse voltage	V <sub>RRM</sub>	200	400	600	V
Reverse voltage, total rms value	V <sub>R(RMS)</sub>	140	280	420	V
Forward current	I <sub>F</sub>	4			А
Peak forward surge current, 8.3ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	75		А	
Junction temperature	TJ	- 55 to +175		°C	
Storage temperature	T <sub>STG</sub>	- 55 to +175		°C	





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THERMAL PERFORMANCE				
PARAMETER	SYMBOL	ТҮР	UNIT	
Junction-to-ambient thermal resistance	R <sub>eja</sub>	45	°C/W	
Junction-to-case thermal resistance	R <sub>eJC</sub>	8.5	°C/W	

ELECTRICAL SPECIFICATIONS (T <sub>A</sub> = 25°C unless otherwise noted)						
PARAMETER		CONDITIONS	SYMBOL	ТҮР	МАХ	UNIT
	MUR420S		V <sub>F</sub>	-	0.875	V
Forward voltage <sup>(1)</sup>	MUR440S MUR460S	I <sub>F</sub> = 4A, T <sub>J</sub> = 25°C		-	1.250	V
Torward voltage	MUR420S			-	0.710	V
	MUR440S MUR460S	$I_F = 4A, T_J = 150^{\circ}C$	V <sub>F</sub>	-	1.050	V
	$ \frac{MUR420S}{MUR440S} T_{J} = 25^{\circ}C $ MUR460S	I <sub>R</sub>	-	5	μA	
Reverse current@ rated $V_{R}^{(2)}$			-	10	μA	
Reverse current@ lated v <sub>R</sub>	MUR420S	$\overline{\text{MUR440S}}  T_{\text{J}} = 150^{\circ}\text{C} \qquad I_{\text{R}}$		-	150	μA
	MUR440S MUR460S		I <sub>R</sub>	-	250	μA
Junction capacitance		$1MHz, V_{R} = 4.0V$	CJ	65	-	pF
	verse recovery time $ \begin{array}{ c c c } \hline MUR420S \\ \hline MUR440S \\ \hline MUR440S \\ \hline MUR460S \\ \hline I_{rr} = 0.25A \\ \hline I_{rr} = 0.25A \\ \hline \end{array} $	I <sub>E</sub> = 0.5A, I <sub>P</sub> = 1.0A		-	25	ns
Reverse recovery time			t <sub>rr</sub>	-	50	ns

#### Notes:

1. Pulse test with PW = 0.3ms

2. Pulse test with PW = 30ms

MUR4xS

ORDERING INFORMATION	l	
ORDERING CODE <sup>(1)</sup>	PACKAGE	PACKING

DO-214AB (SMC)

Notes:

1. "x" defines voltage from 200V(MUR420S) to 600V(MUR460S)



## **CHARACTERISTICS CURVES**

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 

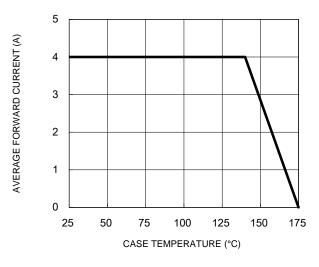
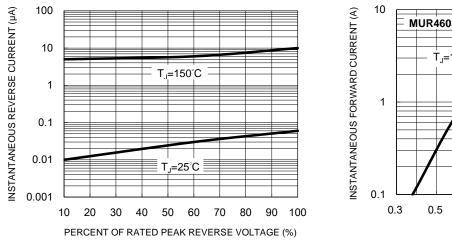


Fig.1 Forward Current Derating Curve

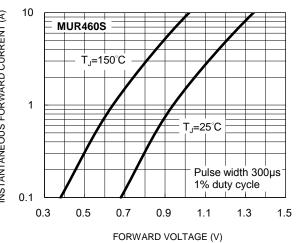
#### **Fig.3 Typical Reverse Characteristics**



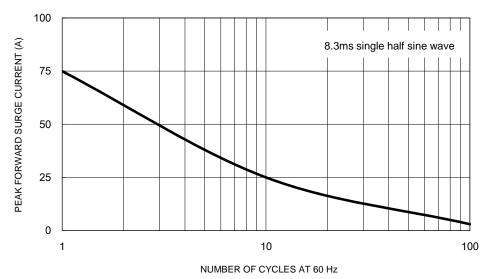
 $(10) \\ (10) \\$ 

#### **Fig.2 Typical Junction Capacitance**

**Fig.4 Typical Forward Characteristics** 



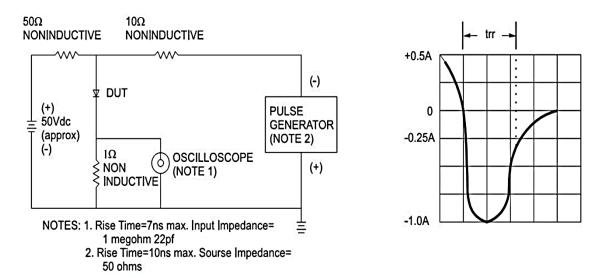
#### Fig.5 Maximum Non-Repetitive Forward Surge Current





## **CHARACTERISTICS CURVES**

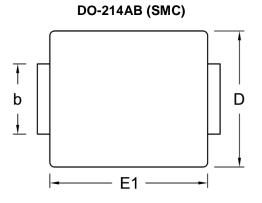
 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 

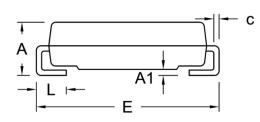


#### Fig.6 Reverse Recovery Time Characteristic and Test Circuit Diagram

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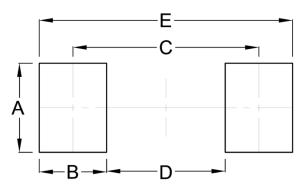
## PACKAGE OUTLINE DIMENSIONS





DIM.	Unit (mm)		Unit	inch)	
Divi.	Min.	Max.	Min.	Max.	
A	2.00	2.62	0.079	0.103	
A1	0.10	0.20	0.004	0.008	
b	2.90	3.20	0.114	0.126	
с	0.15	0.31	0.006	0.012	
D	5.59	6.22	0.220	0.245	
E	7.75	8.13	0.305	0.320	
E1	6.60	7.11	0.260	0.280	
L	1.00	1.60	0.039	0.063	

## SUGGESTED PAD LAYOUT



Symbol	Unit (mm)	Unit (inch)
A	3.30	0.130
В	2.50	0.098
С	6.90	0.272
D	4.40	0.173
E	9.40	0.370

## **MARKING DIAGRAM**



- P/N = Marking Code
- G = Green Compound

YW = Date Code

F = Factory Code



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